

RELIABILITY REPORT FOR
MAX17531AUB+T / MAX17531ATB+T
PLASTIC ENCAPSULATED DEVICES

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MAXIM INTEGRATED

160 RIO ROBLES
SAN JOSE, CA 95134

Approved by
Eric Wright
Quality Assurance
Reliability Engineering

Conclusion

The MAX17531AUB+T / MAX17531ATB+T successfully meet the quality and reliability standards required of all Maxim Integrated products. In addition, Maxim Integrated's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim Integrated's quality and reliability standards.

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I. Device Description

A. General

The MAX17531 high-efficiency, high-voltage, synchronous step-down DC-DC converter with integrated MOSFETs operates over a 4V to 42V input. The converter can deliver up to 50mA and generates output voltages from 0.8V up to $0.9 \times V_{IN}$. The feedback (FB) voltage is accurate to within $\pm 1.75\%$ over -40°C to $+125^{\circ}\text{C}$. The MAX17531 uses peak-current-mode control and can be operated in pulse-width modulation (PWM) or pulse-frequency modulation (PFM) modes. The device is available in a 10-pin (3mm x 2mm) TDFN and 10-pin (3mm x 3mm) $\mu\text{MAX}^{\circledR}$ packages. Simulation models are available.

II. Manufacturing Information

A. Description/Function:	42V, 50mA, Ultra-Small, High-Efficiency, Synchronous Step-Down DC-DC Converter with 22 μ A No-Load Supply Current	
B. Process:	S18	
C. Number of Device Transistors:	22441	
D. Fabrication Location:	Japan	
E. Assembly Location:	Philippines, Thailand	Taiwan, Thailand
F. Date of Initial Production:	December 18, 2014	

III. Packaging Information

A. Package Type:	10-pin μ max	10-pin TDFN
B. Lead Frame:	Copper	Copper
C. Lead Finish:	100% matte Tin	NiPd
D. Die Attach:	Conductive	Non-Conductive
E. Bondwire:	Au (1.3 mil dia.)	Au (1.3 mil dia.)
F. Mold Material:	Epoxy with silica filler	Epoxy with silica filler
G. Assembly Diagram:	#05-9000-5333	05-9000-5330
H. Flammability Rating:	Class UL94-V0	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C	Level 1	Level 1
J. Single Layer Theta Ja:	180°C/W	87.5°C/W
K. Single Layer Theta Jc:	42°C/W	18.2°C/W
L. Multi Layer Theta Ja:	113.1°C/W	67.3°C/W
M. Multi Layer Theta Jc:	42°C/W	18.2°C/W

IV. Die Information

A. Dimensions:	40.9449 X 87.7953 mils
B. Passivation:	Si ₃ N ₄ /SiO ₂ (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Al/0.5%Cu with Ti/TiN Barrier
D. Backside Metallization:	None
E. Minimum Metal Width:	0.23 microns (as drawn)
F. Minimum Metal Spacing:	0.23 microns (as drawn)
G. Bondpad Dimensions:	
H. Isolation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw

V. Quality Assurance Information

- A. Quality Assurance Contacts: Don Lipps (Manager, Reliability Engineering)
Bryan Preeshl (Vice President of QA)
- B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.
0.1% for all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4340 \times 150 \times 2} \quad (\text{Chi square value for MTTF upper limit})$$

(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$\lambda = 7.3 \times 10^{-9}$$

$$\lambda = 7.3 \text{ F.I.T. (60\% confidence level @ 25°C)}$$

The following failure rate represents data collected from Maxim Integrated's reliability monitor program. Maxim Integrated performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at <http://www.maximintegrated.com/qa/reliability/monitor>. Cumulative monitor data for the S18 Process results in a FIT Rate of 0.05 @ 25°C and 0.93 @ 55°C (0.8 eV, 60% UCL)

B. E.S.D. and Latch-Up Testing (lot EATO0Q003E, D/C 1434)

The PI24-1 die type has been found to have all pins able to withstand an HBM transient pulse of +/-2500V per JEDEC JESD22-A114.

Latch-Up testing has shown that this device withstands a current of +/-100mA and overvoltage per JEDEC JESD78
With the following exceptions:

EN/UVLO pin passes +100mA/-75mA per JEDEC JESD78.

RESETB pin passes +100mA/-65mA per JEDEC JESD78.

Table 1
Reliability Evaluation Test Results
MAX17531AUB+T / MAX17531ATB+T

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	COMMENTS
Static Life Test (Note 1)	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality	150	0	EAQK7Q003, D/C 1345

Note 1: Life Test Data may represent plastic DIP qualification lots.